STTH2R02

Ultrafast recovery diode

Main product characteristics

$I_{F(AV)}$	2 A
V_{RRM}	200 V
T_j (max)	175° C
V_F (typ)	0.7 V
t_{rr} (typ)	15 ns

Features and benefits

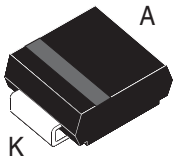
- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery times
- High junction temperature

Description

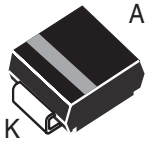
The STTH2R02 uses ST's new 200 V planar Pt doping technology, and it is specially suited for switching mode base drive and transistor circuits.

Packaged in DO-15, SMA, and SMB, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection.

DO-15
STTH2R02Q



SMA
STTH2R02A



SMB
STTH2R02U

Order codes

Part Number	Marking
STTH2R02Q	STTH2R02
STTH2R02QRL	STTH2R02
STTH2R02A	R2A
STTH2R02U	R2U

1 Characteristics

Table 1. Absolute ratings (limiting values at T_j = 25° C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage			200	V
I_{FRM}	Repetitive peak forward current	DO-15(1)	t_p = 5 µs, F = 5 kHz	60	A
		SMA, SMB			
$I_{F(RMS)}$	RMS forward current	DO-15		60	A
		SMA, SMB			
$I_{F(AV)}$	Average forward current, δ = 0.5	DO-15	T_{lead} = 90° C	2	A
		SMA, SMB	T_c = 90° C		
I_{FSM}	Surge non repetitive forward current	t_p = 10 ms Sinusoidal		75	A
T_{stg}	Storage temperature range			-65 to + 175	° C
T_j	Maximum operating junction temperature			175	° C

1. On infinite heatsink with 10 mm lead length

Table 2. Thermal parameters

Symbol	Parameter			Value	Unit
$R_{th(j-c)}$	Junction to lead	Lead Length = 10 mm on infinite heatsink	DO-15	45	° C/W
	Junction to case		SMA, SMB	30	

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ	Max.	Unit
I_R(1)	Reverse leakage current	T_j = 25° C	$V_R = V_{RRM}$			3	µA
		T_j = 125° C			2	20	
V_F(2)	Forward voltage drop	T_j = 25° C	I_F = 6 A			1.20	V
		T_j = 25° C	I_F = 2 A		0.89	1.0	
		T_j = 100° C			0.76	0.85	
		T_j = 150° C			0.70	0.80	

1. Pulse test: t_p = 5 ms, δ < 2 %
2. Pulse test: t_p = 380 µs, δ < 2 %

To evaluate the conduction losses use the following equation:
$P = 0.68 \times I_{F(AV)} + 0.06\ I_F{}^2{}_{(RMS)}$

Table 4. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ	Max.	Unit
t_{rr}	Reverse recovery time	I_F = 1 A, dI_F/dt = -50 A/µs, V_R = 30 V, T_j = 25° C		23	30	ns
		I_F = 1 A, dI_F/dt = -100 A/µs, V_R = 30 V, T_j = 25° C		15	20	
I_{RM}	Reverse recovery current	I_F = 2 A, dI_F/dt = -200 A/µs, V_R = 160 V, T_j = 125° C		3	4	A
t_{fr}	Forward recovery time	I_F = 2 A, dI_F/dt = 100 A/µs V_{FR} = 1.1 x V_{Fmax}, T_j = 25° C		40		ns
V_{FP}	Forward recovery voltage	I_F = 2 A, dI_F/dt = 100 A/µs, T_j = 25° C		2.0		V

Figure 1. Peak current versus duty cycle

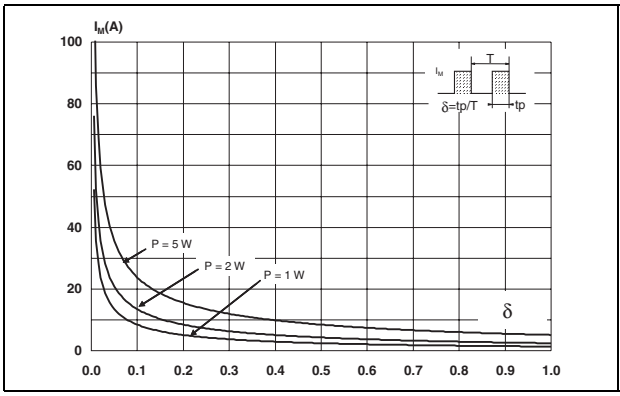


Figure 2. Forward voltage drop versus forward current (typical values)

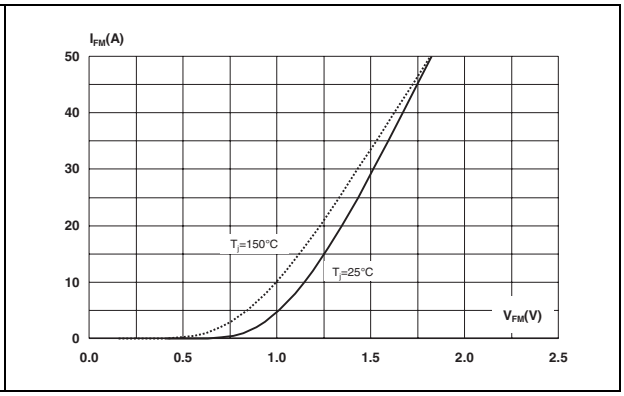


Figure 3. Forward voltage drop versus forward current (maximum values)

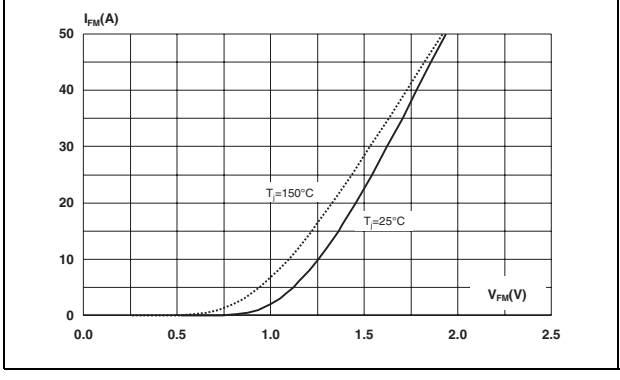


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration (SMA)

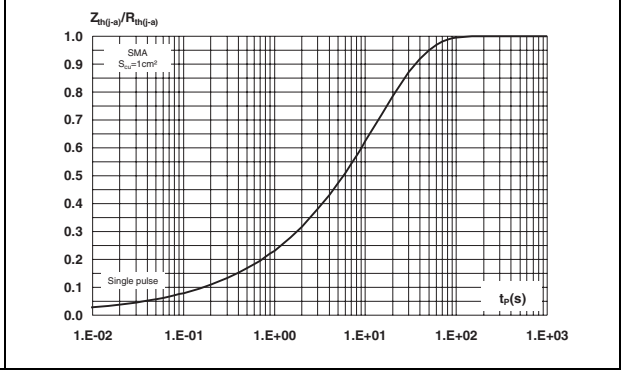


Figure 5. Relative variation of thermal impedance junction to case versus pulse duration (SMB)

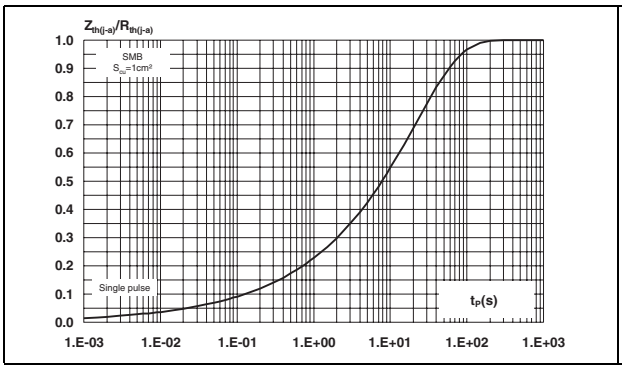


Figure 6. Relative variation of thermal impedance junction to case versus pulse duration (DO-15)

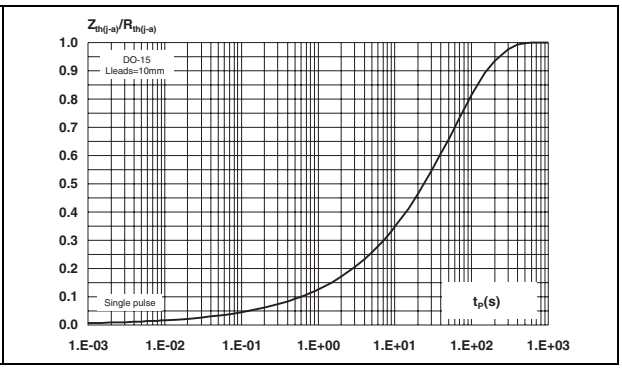


Figure 7. Junction capacitance versus reverse applied voltage (typical values)

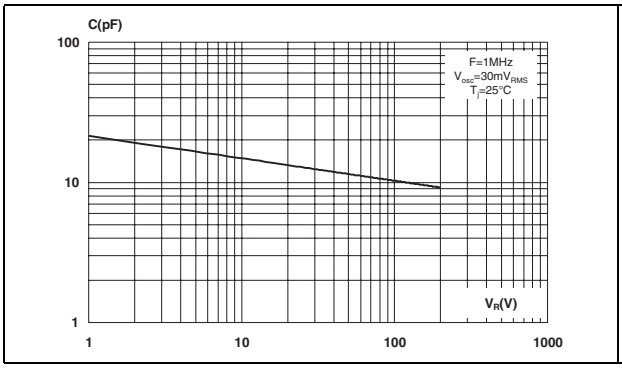


Figure 8. Reverse recovery charges versus dI_F/dt (typical values)

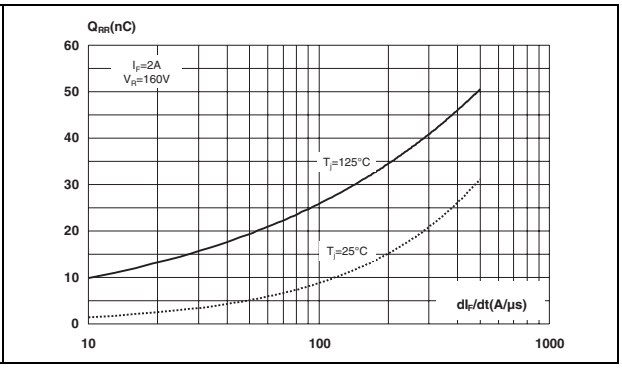


Figure 9. Reverse recovery time versus dI_F/dt (typical values)

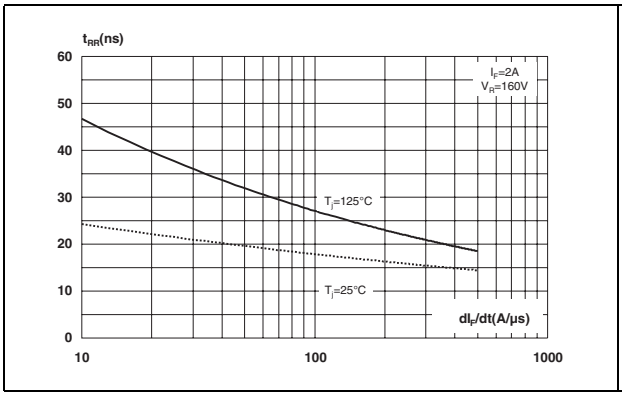


Figure 10. Peak reverse recovery current versus dI_F/dt (typical values)

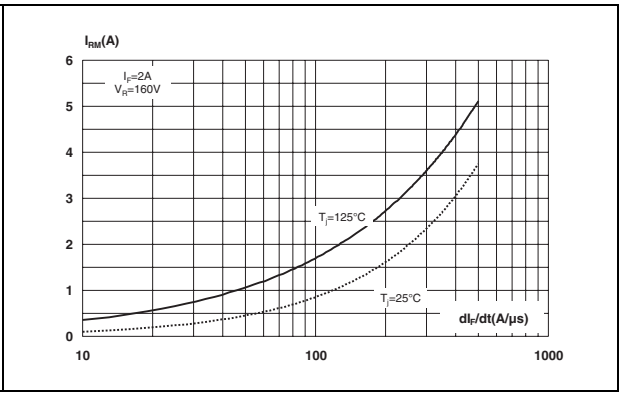


Figure 11. Dynamic parameters versus junction temperature

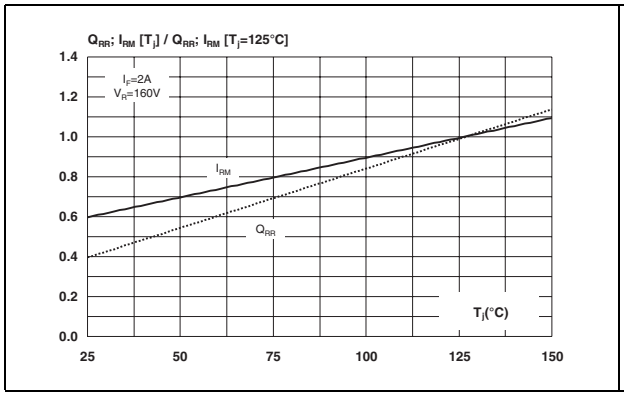


Figure 12. Thermal resistance, junction to ambient, versus copper surface under each lead - SMA/SMB (epoxy FR4, e_{cu} = 35 µm)

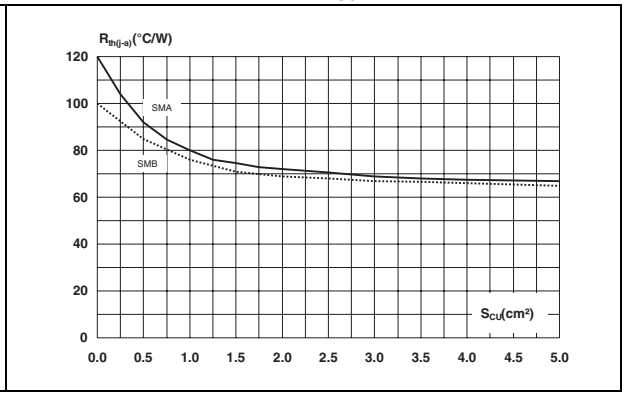
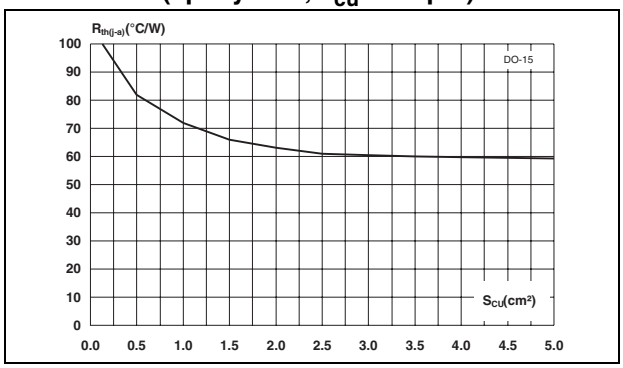
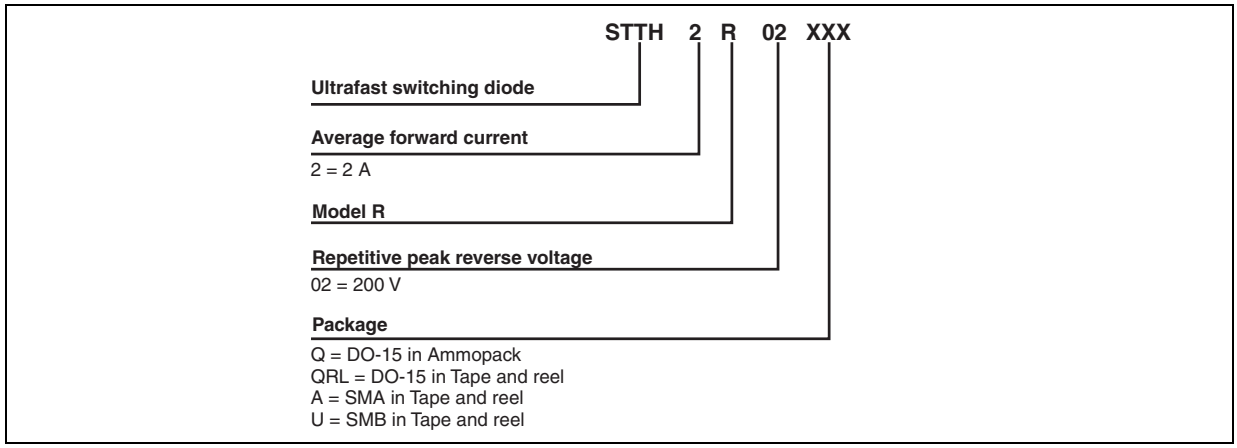


Figure 13. Thermal resistance, junction to ambient, versus copper surface under each lead DO-15 (epoxy FR4, e_{cu} = 35 µm)



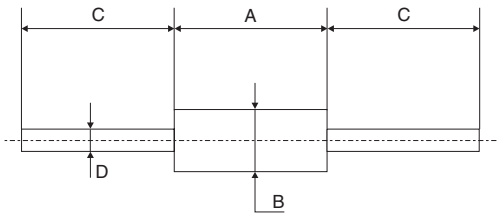
2 Ordering information scheme



3 Package information

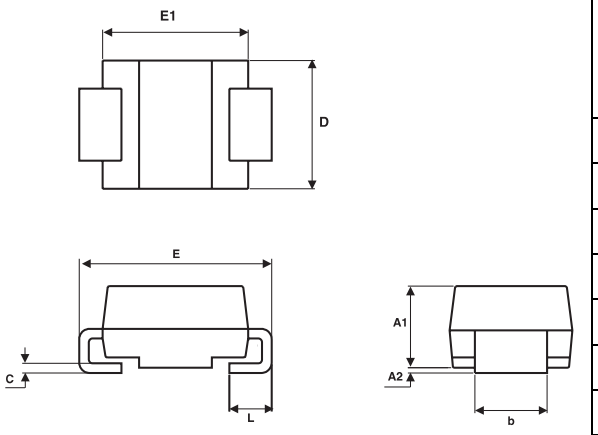
Epoxy meets UL94, V0

Table 5. DO-15 Dimensions



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	6.05	6.75	0.238	0.266
B	2.95	3.53	0.116	0.139
C	26	31	1.024	1.220
D	0.71	0.88	0.028	0.035

Table 6. SMA dimensions



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.03	0.075	0.080
A2	0.05	0.20	0.002	0.008
b	1.25	1.65	0.049	0.065
c	0.15	0.41	0.006	0.016
E	4.80	5.60	0.189	0.220
E1	3.95	4.60	0.156	0.181
D	2.25	2.95	0.089	0.116
L	0.75	1.60	0.030	0.063

Figure 14. SMA footprint (dimensions in mm)

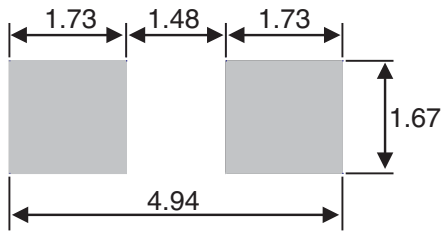
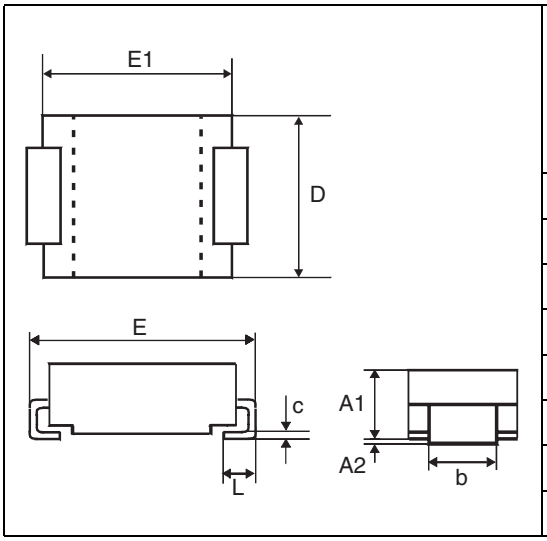
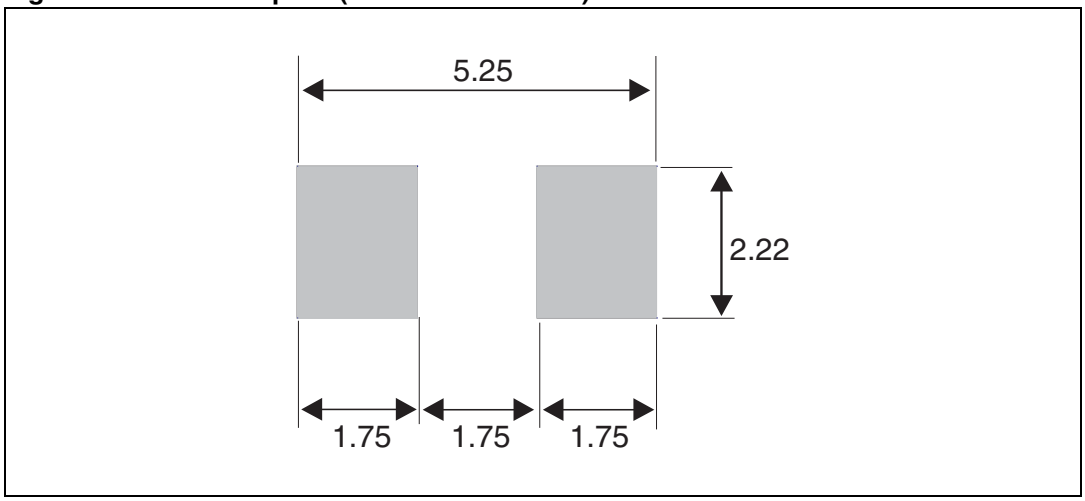


Table 7. SMB dimensions



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.		Max.	Min.		Max.
A1	1.90	2.15	2.45	0.075	0.085	0.096
A2	0.05	0.15	0.20	0.002	0.006	0.008
b	1.95		2.20	0.077		0.087
c	0.15		0.41	0.006		0.016
E	5.10	5.40	5.60	0.201	0.213	0.220
E1	4.05	4.30	4.60	0.159	0.169	0.181
D	3.30	3.60	3.95	0.130	0.142	0.156
L	0.75	1.15	1.60	0.030	0.045	0.063

Figure 15. SMB footprint (dimensions in mm)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

4 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH2R02Q	STTH2R02	DO-15	0.4 g	1000	Ammopack
STTH2R02QRL	STTH2R02	DO-15	0.4 g	6000	Tape and reel
STTH2R02A	R2A	SMA	0.068 g	5000	Tape and reel
STTH2R02U	R2U	SMB	0.12 g	2500	Tape and reel

5 Revision history

Date	Revision	Description of Changes
03-May-2006	1	First issue
13-Oct-2006	2	Maximum T_j set to 175° C for all packages in Table 1.

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